

HIGH VOLTAGE POWER SCHOTTKY RECTIFIER

MAIN PRODUCT CHARACTERISTICS

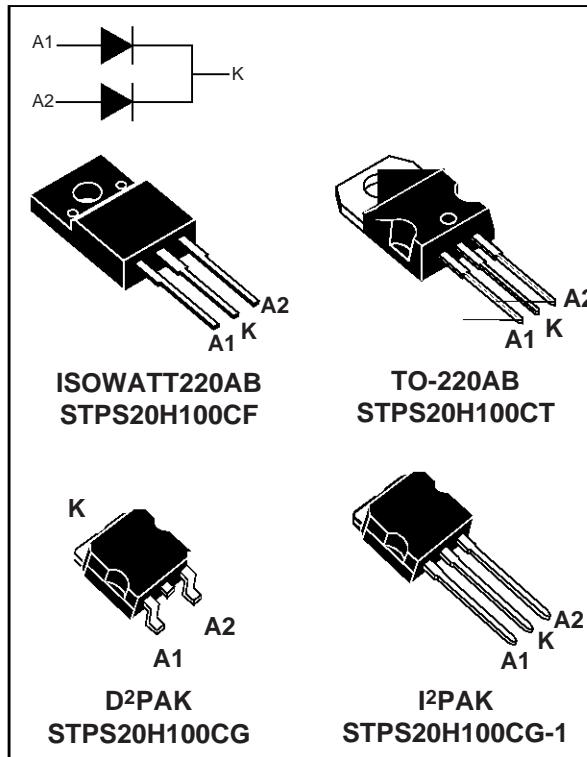
$I_{F(AV)}$	2 x 10 A
V_{RRM}	100 V
T_j	175°C
V_F (max)	0.64 V

FEATURES AND BENEFITS

- NEGLIGIBLE SWITCHING LOSSES
- HIGH JUNCTION TEMPERATURE CAPABILITY
- GOOD TRADE OFF BETWEEN LEAKAGE CURRENT AND FORWARD VOLTAGE DROP
- LOW LEAKAGE CURRENT
- AVALANCHE RATED
- INSULATED PACKAGE: ISOWATT220AB
Insulating Voltage = 2000V DC
Capacitance = 45 pF

DESCRIPTION

Dual center tap schottky rectifier designed for high frequency miniature Switched Mode Power Supplies such as adaptors and on board DC/DC converters.



ABSOLUTE RATINGS (limiting values, per diode)

Symbol	Parameter				Value	Unit		
V_{RRM}	Repetitive peak reverse voltage				100	V		
$I_{F(RMS)}$	RMS forward current				30	A		
$I_{F(AV)}$	Average forward current $\delta = 0.5$	TO-220AB	$T_c = 160^\circ\text{C}$	per diode per device	10	A		
		D ² PAK / I ² PAK			20	A		
		ISOWATT220AB	$T_c = 145^\circ\text{C}$					
I_{FSM}	Surge non repetitive forward current		$t_p = 10 \text{ ms sinusoidal}$		250	A		
I_{RRM}	Repetitive peak reverse current		$t_p = 2 \mu\text{s square } F = 1\text{kHz}$		1	A		
I_{RSR}	Non repetitive peak reverse current		$t_p = 100 \mu\text{s square}$		3	A		
T_{stg}	Storage temperature range				- 65 to + 175	°C		
T_j	Maximum operating junction temperature *				175	°C		
dV/dt	Critical rate of rise of reverse voltage				10000	V/ μ s		

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th}(j - a)}$ thermal runaway condition for a diode on its own heatsink

STPS20H100CT/CF/CG/CG-1

THERMAL RESISTANCES

Symbol	Parameter			Value	Unit
$R_{th}(j-c)$	Junction to case	TO-220AB / D ² PAK / I ² PAK	Per diode	1.6	°C/W
		ISOWATT220AB	Per diode	4	
		TO-220AB / D ² PAK / I ² PAK	Total	0.9	°C/W
		ISOWATT220AB	Total	3.2	
$R_{th}(c)$		TO-220AB / D ² PAK / I ² PAK	Coupling	0.15	°C/W
		ISOWATT220AB	Coupling	2.5	

When the diodes 1 and 2 are used simultaneously :
 $\Delta T_j(\text{diode 1}) = P(\text{diode 1}) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode 2}) \times R_{th(c)}$

STATIC ELECTRICAL CHARACTERISTICS (per diode)

Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
I_R *	Reverse leakage current	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			4.5	μA
		$T_j = 125^\circ\text{C}$			2	6	mA
V_F **	Forward voltage drop	$T_j = 25^\circ\text{C}$	$I_F = 8 \text{ A}$			0.71	V
		$T_j = 25^\circ\text{C}$	$I_F = 10 \text{ A}$			0.77	
		$T_j = 25^\circ\text{C}$	$I_F = 16 \text{ A}$			0.81	
		$T_j = 25^\circ\text{C}$	$I_F = 20 \text{ A}$			0.88	
		$T_j = 125^\circ\text{C}$	$I_F = 8 \text{ A}$		0.56	0.58	
		$T_j = 125^\circ\text{C}$	$I_F = 10 \text{ A}$		0.59	0.64	
		$T_j = 125^\circ\text{C}$	$I_F = 16 \text{ A}$		0.65	0.68	
		$T_j = 125^\circ\text{C}$	$I_F = 20 \text{ A}$		0.67	0.73	

Pulse test : * $t_p = 5 \text{ ms}, \delta < 2\%$
** $t_p = 380 \mu\text{s}, \delta < 2\%$

To evaluate the maximum conduction losses use the following equation :

$$P = 0.55 \times I_{F(AV)} + 0.009 \times I_{F(RMS)}^2$$

Fig. 1: Average forward power dissipation versus average forward current (per diode).

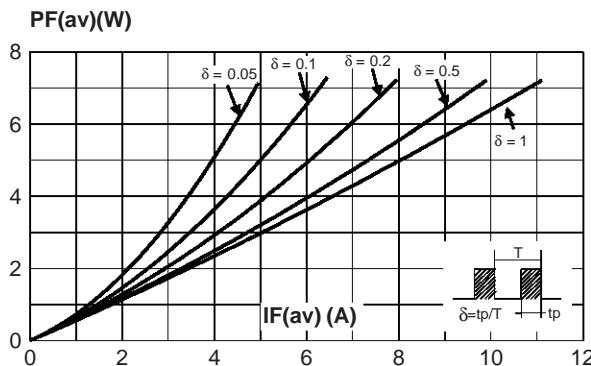
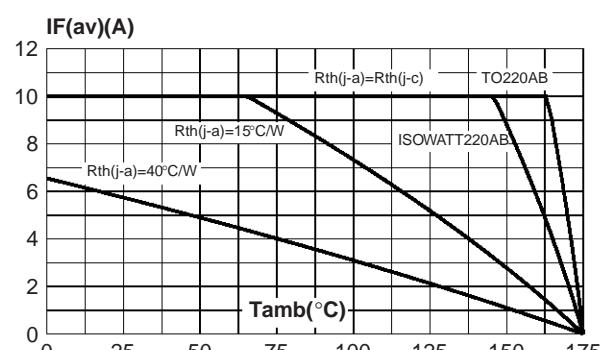
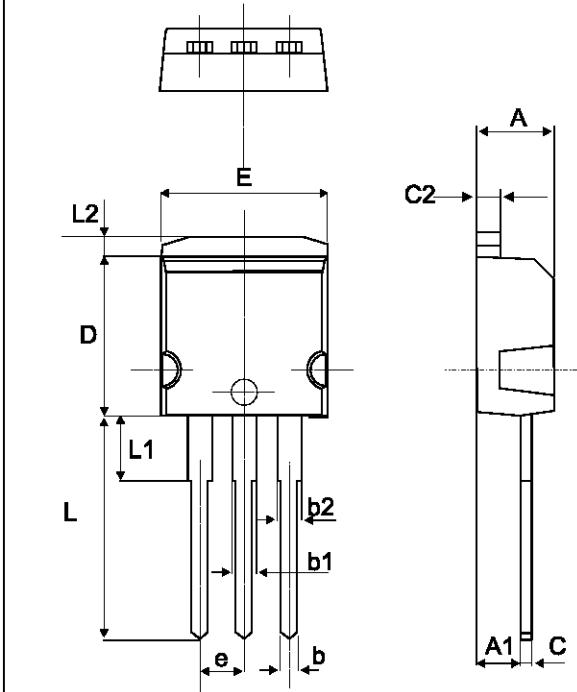


Fig. 2: Average forward current versus ambient temperature ($\delta=0.5$, per diode).



PACKAGE MECHANICAL DATA
I²PAK


REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.30		4.60	0.169		0.181
A1	2.49		2.69	0.098		0.106
b	0.70		0.93	0.028		0.037
b1	1.20		1.38	0.047		0.054
b2	1.25	1.40		0.049	0.055	
C	0.45		0.60	0.018		0.024
C2	1.21		1.36	0.048		0.054
D	8.95		9.35	0.352		0.368
e	2.44		2.64	0.096		0.104
E	10.00		10.28	0.394		0.405
L	13.10		13.60	0.516		0.535
L1	3.48		3.78	0.137		0.149
L2	1.27		1.40	0.050		0.055

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS20H100CT	STPS20H100CT	TO-220AB	2.20g	50	Tube
STPS20H100CF	STPS20H100CF	ISOWATT220AB	2.08g	50	Tube
STPS20H100CG-1	STPS20H100CG	I ² PAK	1.49g	50	Tube
STPS20H100CG	STPS20H100CG	D ² PAK	1.48g	50	Tube
STPS20H100CG-TR	STPS20H100CG	D ² PAK	1.48g	1000	Tape & reel

^a Epoxy meets UL94,V0